




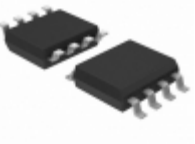
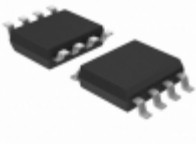


	<p>SI4348DY-T1-E3</p>
	<p>Hersteller-Teilenummer: SI4348DY-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 8A 8-SOIC</p> <p>Datenblätter:  SI4348DY-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 900574 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI4348DY-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 30V 8A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	900574 pcs Stock
Hersteller Standard Vorlaufzeit	21 Weeks
detaillierte Beschreibung	N-Channel 30V 8A (Ta) 1.31W (Ta) Surface Mount 8-
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Verlustleistung (max)	1.31W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8A (Ta)
Rds On (Max) @ Id, Vgs	12.5 mOhm @ 11A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 4.5V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI4348DY-T1-E3TR




SI4348DY-T1-E3 ist neu im Original, Suche SI4348DY-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4348DY-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI4348DY-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI4335 SI SI4335 SI</p>	 <p>SI4348DY Vishay Precision Group SI4348DY VISHAY</p>	 <p>SI4354DY-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 9.5A 8-SOIC</p>	 <p>SI4354DY-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 9.5A 8-SOIC</p>
 <p>SI4346DY-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 5.9A 8-SOIC</p>	 <p>SI4346DY-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 5.9A 8-SOIC</p>	 <p>SI4346DY-T1-GE3 VISHAY SI4346DY-T1-GE3 VISHAY</p>	 <p>SI4348DY-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 8A 8-SOIC</p>

heiße Teile

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|---|---|---|--|---|
|  SI4324DY-T1-E3 |  SI4326DY-T1-E3 |  SI4330BDY-T1-GE3 |  SI4330DY-T1 |  SI4330DY-T1-E3 |
|  SI4330DY-T1-E3 |  SI4330DY-T1-E3 |  SI4334DY-T1-E3 |  SI4336DY |  SI4336DY-E3 |
|  SI4336DY-T1-E3 |  SI4336DY-T1-E3 |  SI4340CDY-T1-E3 |  SI4340CDY-T1-E3 |  SI4340CDY-T1-E3-S |
|  SI4340DY |  SI4340DY-T1 |  SI4340DY-T1-E3 |  SI4340DY-T1-E3 |  SI4346DY |
|  SI4346DY-T1-E3 |  SI4346DY-T1-E3 |  SI4346DY-T1-GE3 |  SI4346DY-T1-GE3 |  SI4348DY |
|  SI4348DY-T1-E3 |  SI4348DY-T1-GE3 |  SI4354DY-T1-E3 |  SI4354DY-T1-E3 |  SI4355-B1A-FMR |
|  SI4356ADY-T1-E3 |  SI4356DY |  SI4356DY-T1 |  SI4356DY-T1-E3 |  SI4362BDY |
|  SI4362BDY-T1-E3 |  SI4362BDY-T1-E3 |  SI4362BDY-T1-E3-PBF |  SI4362DY |  SI4362DY-T1 |
|  SI4362DY-T1-E3 |  SI4362DY-T1-E3 |  SI4364DY |  SI4364DY-T1 |  SI4364DY-T1-E3 |
|  SI4366DY-T1-E3 |  SI4368DY |  SI4368DY-T1-E3 |  SI4368DY-T1-E3 |  SI4370DY-T1-E3 |

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